

Superconductivity Modulated by Binary Doping in Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x}

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Abstract

Binary doping effect is studied for the Fe-based superconductors of Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x} (x = 0.02, 0.05, 0.1, 0.15, 0.2). The X-ray diffractions show that the *c*-axis lattice constant decreases monotonously with the doping content, in contrast to the little change in the *a*-axis. Temperature dependences of electric resistivity and magnetic susceptibility reveal that the superconductivity for the studied system emerges at x = 0.1, and enhances together with $H_{c2}(0)$ as the doping content x increases further. In case of x = 0.2, the superconducting critical temperature reaches as high as 50 K, which is the first demonstration of superconductivity with a high fluorine-doping induced by both electron and hole doping in this family. Negative Hall coefficient (R_H) indicates that electron-type carriers are dominated in the present samples. The complicated temperature dependence of R_{H_2} , is believed to arise from a multiband effect together with a complicated scattering, especially at the temperature near the T_c .

Keywords: Binary Doping, Iron-Based Superconductor, Flux Pinning, Scattering

1. Introduction

The fantastic discovery of superconductivity with the transition temperature T_c of around 26 K [1] in the new class of iron-arsenide has attracted wide interest in the world. Among the family of Fe-based superconductors, the LaFeAsO_{1-y} (FeAs-1111) exhibits quite high critical temperatures, such as $T_c = 55$ K [2] in the case of electron doping like SmFeAsO_{1-x}F_x, and $T_c = 25$ K [3] in the case of hole doping like La_{1-x}Sr_xFeAsO.

It is well known that there are other types of ironpnictide superconductors, among which the FeAs_{1-y} (FeAs-11), a type of Fe-chalcogenide superconductor, attracts a lot of attentions due to its simple structure and composition [4]. It is reported that the FeAs-11 exhibits the zero resistance transition temperature of 8 K for the PbO-type α -FeSe compound [5], while the Li_xFeAs (FeAs-111), as an infinite layered structure [6,7] may exhibit the T_c of 18 K without SDW phases.

In contrast, the FeAs-1111 involves two types of par-

ent compounds [1], *i.e.*, LnFeAsO (Ln is rare earths) and AFeAsF (A is positive bivalent ion), both exhibiting the tetragonal space group *P*4/nmm at 300 K. The first one shows an anomaly of magnetic phase transition near 150 K, which is believed to be caused by the spin-density-wave (SDW) instability [8]. This kind of Fe-based superconductor is characterized as electron-doped [9-13] and its T_c may be enhanced to be 55 ~ 56 K via replacing lanthanum with other rare-earth elements. [2,9-14] The second parent compound such as SrFeAsF being of ZrCuSiAs-tpye structures [15,16], shows an SDW and/or structural transition at about 173 K, and its positive Hall coefficient ($R_{\rm H}$) suggesting that the conduction of this parent phase is dominated by hole-like charge carriers. [14]

According to existing investigations, the parent compounds of both LnFeAsO and AFeAsF show the SDW but no superconductivity, and they can evolve into superconductors as a consequence of the normative symmetry breaking due to the element doping, such as $Gd_{1-x}Th_xFeAsO$ [13] $SmFe_{0.9}Co_{0.1}AsO$ [17], $CeFeAs_{1-x}P_xO$ [18], and $LaFeAsO_{1-x}F_x$ [1]. Similar phenomena also exists in FeAs-122 system, such as $Ca_{1-x}Na_xFe_2As_2$ [19], $Ba(Fe_{0.961}Ru_{0.039})_2As_2$ [20], $EuFe_2(As_{0.7}P_{0.3})_2$ [21] and so on.

With respect to the FeAs-1111 system, the fluorine doping or oxygen deficiency related to the oxygen-site is frequently studied [22,23], disclosing that they are effective to produce the superconductivity. For FeAs-11 system, it is reported that the clean superconducting phase exists only in those samples with intentional Se deficiency [24,25], and single crystal samples are hardly obtained with a stoichiometric composition of 1:1. All of these suggest that the superconductivity may emerge or be enhanced by element substitution due to normative symmetry breaking in electronic structure, charge or stress etc.

Apart from one element or one site substitution, it is also reported that the second element doping at other site is applicable to modify the normative symmetry and then the superconductivity [26-28], such as $Ce_{1-x}Gd_x$

 $FeAsO_{0.84}F_{0.16}$ [26], and $SmFe_{1-x}Ru_xAsO_{0.85}F_{0.15}$ [27].

Compared with the case of one site doping, two element substitutions or doping may exhibit more unique phenomenon. In the present paper, we focus on the FeAs-1111 system and study its doping effect using binary substitution, namely Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x}. This special system with both electron-doping and hole-doping allow more breaking of original symmetry, and this may give rise to complicate modification for superconducting and magnetic behaviors. In the flowing sections, the structural and electromagnetic characteristics regarding this system are systemically investigated, to understand its distinct performances and underlying mechanism due to binary doping.

2. Experimental

Polycrystalline bulks with nominal compositions of $Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x}$ (x = 0.02, 0.05, 0.1, 0.15, and 0.2) were synthesized by conventional solid-state reaction. Firstly, the intermediate phases of Fe₂As, NdAs and FeO were prepared by the reactions of the mixed commercial powders of Nd (99.5%), Fe (99.9%), As (99.999%) and Fe₂O₃ (99.9%), sealed in a vacuum quartz tube, annealed at 600°C for 6 h and then 850°C for 12 h.

Subsequently, the resultant precursors together with BaF_2 powder in stoichiometry of $Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x}$ were ground for 15 min. All the weighing and mixing procedures were performed in a glove box filled with high purity Ar gas. After that, the mixtures pressed to into pellets in diameter of 8mm, were sealed in a vacuum quartz tube, and then heated up to 1160°C by a rate of

230°C/h. For the reference, the pellets are divided into two sorts, with and without surface wrapping by Ta pieces [29] to test the effect of preventing fluorine-volatilizing during the solid-state reaction.

Note that the present precursors with and without Ta wrapping were maintained at the temperature of 1160°C for 10 h only, rather than several ten hours reported by others. This is purposely selected as we believe that it is critical to shorten the heating time to avoid the fluorine-volatilizing at high temperatures, and to increase the synthesis efficiency as well.

The crystal structure and phase purity of all studied samples were characterized by X-ray diffraction (XRD). The superconducting properties were measured by using a physical property measurement system (Quantum Design PPMS) in magnetic fields up to 9 T. Magnetic and transport performances are evaluated by a series of characteristic curves including the temperature dependences of resistivity, dc susceptibility, and the Hall coefficient etc. For the magnetization measurements, rectangular specimens were prepared nearly in the same dimension of about $6 \times 2 \times 1 \text{ mm}^3$, and the applied magnetic fields were normal to the long axis direction of the specimen.

3. Result and Discussion

3.1. Microstructure, Lattice Constants and Their Doping Dependences

The XRD patterns for the samples with various doping contents of 0.02 - 0.2 are shown in **Figure 1**. It is clear that the main peaks for all studied samples can be indexed to the FeAs-1111 phase with the tetragonal ZrCuSiAs-type structure, regardless of the slight shift of main peaks and several weak peaks corresponding with the impurity phase of NdOF.

The doping dependence of the lattice constants calculated from the XRD data are presented in Figure 2. There is little change in the lattice constants of *a*-axis as the doping content increases. This may result from the contrary contributions to the in-plane lattice from two elements doping, since the ionic radius of Ba²⁺ is larger than that of Nd^{3+} , while the ionic radius of F^- is smaller than that of O^{2-} . In contrast, the *c*-axis lattice constants decrease monotonously with the doping content. Such a reduction probably arises from the decrease in layer distance between FeAs and NdO which may take places due to chemical pressure variation along the *c*-axis [30]. Note that this is unlike the case of hole-like system such as Pr_{1-x}Sr_xFeAsO [31] and Nd_{1-x}Sr_xFeAsO [32], where the *c*-axis lattices increase monotonously with increasing the doping content of Sr. It is thus observed that the *c*-axis lattice increase with the doping content is mostly present



Figure 1. (Colour online) X-ray diffraction patterns for the $Nd_{1-x}Ba_xFeAsO_{1-2x}F_{2x}$ compounds with various doping contents from x = 0.02 (bottom) to x = 0.2 (top).



Figure 2. (Colour online) Doping content dependence of *a*-axis and *c*-axis lattice constants.

in hole-like doping FeAs-1111 system, while *c*-axis decrease with the doping mostly in electron-like doping. With respect to the chemical pressure change, it is supposed that a further increase in T_c may emerge with more BaF₂ chemically doped into the FeAs-1111 system [33].

3.2. Phase Diagram Regarding Superconductivity and SDW Transition

Characteristic transition temperatures are evaluated by both R-T curve and dc susceptibility measurements. **Figure 3(a)** shows the R-T curves for the samples with various doping contents prepared by solid-state reaction without Ta wrapping. To test the stability of the samples, **Figure 3(b)** shows the superconducting critical temperature as well as its transition width, identified from the *R*-*T* curves in **Figure 3(a)**. It is revealed that the present samples exhibit the superconductivity as x is more than 0.1, being as high as 50 K at x = 0.2. Moreover, the superconducting transition width ΔT , determined by the temperatures corresponding to 90% and 10% of the normal-state resistivity, decreases with increasing doping content, being as low as 1.86 K at x = 0.2.



Figure 3. (colour online) (a) Temperature dependence of resistivity for the studied samples with x = 0.05, 0.1, 0.15, and 0.2. Inset shows two *R*-*T* curves for the same sample of x = 0.15, measured before and after 5 months, respectively; (b) The doping content dependence of T^{onset}_{c} and ΔT (determined by the difference of $T^{10\%}_{c}$ and $T^{10\%}_{c}$.

To further confirm the transport results, the temperature dependences of dc susceptibility are measured by ZFC (zero field cooling) and FC (field cooling) modes with an excitation field of 1000e. **Figure 4** shows the temperature dependences of the volume magnetic susceptibility for two typical samples of x = 0.15 and x =0.2, demonstrating their onset superconducting critical temperatures of 44.2 K and 48.8 K, respectively.

Note that the T_c measured by dc susceptibility is a little lower than the values measured by transport due to percolation effect. They are, however, close to the values of $T_c^{50\%}$ dominated by the 50% of the normal state resistivity, which is frequently observed for Fe-base superconductors. Moreover, the width of magnetic transition is generally larger than that of resistivity, which is due to the magnetic signal out of statistic results for whole grains, being more sensitive than the transport.

Apart from superconducting transition temperatures, another characteristic temperature T_s regarding the phase transition of SDW, can be identified as well based on the temperature dependences of resistance and dc susceptibility. For the sample of x = 0.05, no superconductivity is observed, while a SDW transition temperature of 117 K is clearly demonstrated.

Figure 5 shows a phase diagram with respect to the doping content dependence of characteristic temperatures. including the SDW transition temperature T_s and the superconducting transition temperature T_c for all studied samples. It is revealed that the samples with and without Ta wrapping exhibit similar dependence of the doping content. The superconductivity appears at x > 0.1, and it still exists at a high doping content, e.g. x = 0.2. While the T_s is hardly affected by wrapping condition, the T_c for the sample without wrapping is generally high than the sample with wrapping. This implies that a different wrapping way will lead to a different T_c , regardless of identical composition and heating route, This is probably due to suppressed fluorine-evaporating as well as F doping content in the case of wrapping, which reminds us of selecting the samples only without Ta wrapping, which give a relatively high T_c , for more meaningful discussions below.

For the samples of x = 0.15 and x = 0.2, a clear superconducting transition is observed due to effective fluorine doping, and a metallic characteristic in normal state with a good linear dependence of *R*-*T*. The sample of x =0.1, however, shows a little complicated temperature dependence of resistance, as this compound lies the boundary of the superconducting area in the phase diagram. An upturn peak of resistance occurs at the temperatures close to T_c , followed by a semiconductor-like behavior, and then a metallic characteristic as the temperature increases.



Figure 4. (Colour online) Temperature dependences of ZFC and FC magnetization curves for the samples of x = 0.15 (a) and x = 0.2 (b).



Figure 5. (Colour online) Phase diagram with respect to the superconducting and SDW Transition, determined by the doping dependence of characteristic temperatures for the samples with or without Ta wrapping treatment.

Similar behavior was also observed in NdFe_{1-x}Rh_xAsO [34] and it was assumed that such a semiconductor-like behavior actually was one of natures of this family, which was unambiguously proved by band structure calculations as well as photoemission spectroscopy experiments [35]. For the present case, as x increases, both the T_c and ΔT are improved due to the increase of BaF₂ doping content, and then a more rigid metallic characteristic that eventually hides the semiconductor-like nature at all. This assumption is in consistent with the observation of the residual resistance ratio ($RRR = R(300 \text{ K})/R(T_c)$, which is enhanced from 1.93 to 5.5 as the BaF₂ doping content of x increases from 0.1 to 0.2.

3.3. Characteristic Magnetic Fields

Figure 6 shows the temperature dependences of resistivity under different magnetic fields for the sample of x = 0.15 and 0.2. Based on the magnetotransport measurements, two types of characteristic magnetic fields, irreversibility fields (H_{irr}) and upper critical fields (H_{c2}) are



Figure 6. (Colour online) Temperature dependences of resistance under various magnetic fields for two samples of x = 0.15 (a) and x = 0.2 (b).

determined by the criterion of 10% and 90% of normal-state resistivity, respectively. Note that similar evaluation are widely applied to YBaCuO, MgB₂, the F-doped LaFeAsO and Sr-doped PrFeAsO polycrystalline samples [31,36,37].

Figure 7(a) shows the relations between the reduced temperature and characteristic magnetic fields. It is revealed that both H_{irr} and H_{c2} are enhanced with increasing x from 0.1 to 0.2. In case of x = 0.2, the $H_{irr}(T)$ curve is closer to $H_{c2}(T)$ curve, which implies that the stronger flux pinning effect hinders the dissipating resistance due to flux jumping.

Figure 7(b) shows the slopes of $H_{c2}(T)$ near T_c for several superconducting samples with higher doping content of x. By using the Werthamer-Helfand Hohenberg (WHH) theory, the zero temperature upper critical field $H_{c2}(0)$ can be evaluated by the formula below,

$$H_{c2}\left(0\right) = -0.693T_{c}\left(\frac{\mathrm{d}H_{c2}}{\mathrm{d}T}\right)_{T=T_{c}}$$

Taking $T_c = 50$ K for x = 0.2 sample, one can get the $H_{c2}(0)$ of 163 T. As well, $H_{c2}(0)$ is calculated to be 110 T, and 43 T for x = 0.15 and x = 0.1, respectively. Note that these $H_{c2}(0)$ values are actually lower than that of SmFeAs(OF) [38], and FeAs-42622 family [16]. However, the slope of $\left. \frac{dH_{c2}}{dT} \right|_{T_{c2}}$ for the present sample of x = 0.2 is much larger than that of hole doped Pr_{1-x}Sr_xFeAsO [31], and also than that of electron doped LaFeASO_{1-x} F_x) [36,37]. Obviously, the values of upper critical field in the case of the binary doping are much more sensitive than that of single element doping. This suggests that the present system with both electron-doping and hole-doping gives rise to more breaking of original symmetry, and then more modification for superconducting behaviors. A direct mechanism may arise from the increased quasiparticle density of states (DOS) near the Fermi level due to both electron and hole doping.

3.4. Hall Effect and Dominant Carriers

To get more information about the conducting carriers, the Hall coefficient (R_H) of all samples are measured using the five-probe technique. The deliberated binary doping probably allow more symmetry breaking of the electronic structure, compared with the cases of sole hole doping or electron doping, and this will give rise to the more disorders of internal structure of the compound. **Figure 8** shows the temperature dependences of R_H for the samples of x = 0.05, 0.10, and 0.20. The negative Hall coefficient R_H indicates that the electron-type carriers dominate the conduction in the present samples, although the binary doping is purposely designed. This is



Figure 7. (Colour online) (a) Reduced temperature dependence of H_{irr} and H_{c2} for x = 0.1, 0.15, 0.2. (b) Doping content dependence of $\mu_0 dH d_{90\%}/dT$ and $H_{c2}(0)$; the inset shows the Doping content dependence of $\mu_0 dH d_{10\%}/dT$.

reasonable if one recall the difference in doping level between Oxygen and Neodymium site. The former is double of the later, leading to the breaking of normative system in electron structure. This is in agreement with the observation of the c-axis lattices, which decreases monotonously with increasing the doping content, unlike the case of hole-doped FeAs-1111 system, as discussed in the prior section.

It is well known that the Hall coefficient R_H is nearly independent of temperature for conventional metals [31], Whereas, a strong temperature dependence of R_H occurs in high-temperature oxide superconductors, and it is regarded as one of the exotic properties. For the present FeAs-based superconductor, the SDW transition may occur at 117 K, while its superconductivity does not emerge at all, such as in the sample of x = 0.05. For this



Figure 8. (Colour online) Temperature dependence of Hall coefficiency for the samples of x = 0.05, 0.1, 0.15, 0.2. It is seen that the R_H has a sharp transition near the T_c , and the electron-type carriers are dominated for all the studied samples.

composition, the temperature dependence of R_H is comparatively simple, *i.e.*, the absolute value decreases monotonously with increasing temperature.

A band structure calculation for LaFePO indicates that all the *d*-orbital energy levels for five Fe atoms in FeAs-1111 superconductors are not fully occupied, and the cross of the Fermi level E_F , leads to five Fermi surfaces [39]. Therefore, it is believed that the temperature dependence of R_H arises from the multiband effects or magnetic skew scattering mechanism alternatively. Note that the scattering of conduction electrons from local moments is asymmetric due to spin-orbital coupling. A rough estimated from the relation of $n = 1/(e^*R_H)$, indicates the carrier density for our present samples is nearly around 1.6×10^{22} cm⁻³ at the normal state, being 10 times larger than that of LaFeAsO_{0.9}F_{0.1-y} [37].

For further increase of BaF₂ doping, temperature dependence of R_H become stronger, although the monotonous trend still exists. For the present samples of x = 0.1 and x = 0.15, the temperature dependence of R_H exhibits a similar behavior. As the temperature increases, the R_H jumps from a large negative value to a small constant, which actually corresponds to the phase transition around T_c .

In the case of x = 0.2, the monotonic change disappears and the temperature dependence of R_H becomes complicated. Nevertheless, a common feature remains for such a sample, *i.e.* the R_H undergoes a dramatic transition near the superconducting critical temperature. The carrier density slow decrease to 1.2×10^{22} cm⁻³ at 60 K from the normal state, when it turns into SC state, the

value rapid decline to 0.255×10^{22} cm⁻³at 40 K, while the further low temperature makes the value dramatically shot up to 6.25×10^{24} cm⁻³. At the temperature below 30 K, the value of R_H is close to zero. As the temperature increases, it becomes a large negative value firstly, and then upturns to be a small constant up to 240 K, and finally goes to increase until 300 K.

The above temperature dependence appears unusual. It, however, is not hard to understand if one recalls the multi-band effect together with a complicated scattering [3,14,40-42], by which a similar scenario in the hole-like $Pr_{1-x}Sr_xFeAsO$ [31] can be explained well.

It is believed that the present samples follow a strong multi-band effect with a large variation of charge carrier densities as well, especially at the high doping content where the nominal composition of F reaches as high as 40%. These factors suggest that the resultant R_H is probably weighted by the sum of the contributions from each band. Assuming that the scattering rate of each band has different temperature dependence, it is reasonable to see the weighted sum change with temperature. In reality, both the effects are able to make collective contributions to the Hall signal in the present $Nd_{1-x}Ba_x$ $FeAsO_{1-2x}F_{2x}$ since the electrons are dominant carries in this system.

4. Summary

Effect of binary doping on the compound of Nd_{1-x}Ba_x FeAsO_{1-2x}F_{2x} has been investigated with respect to distinct structural and superconducting properties. It is revealed that the c-axis lattice constants decrease monotonously with increasing doping content. In case of x > 0.1, the magnetic order of SWD may be destroyed and superconductivity takes places, which are confirmed by the measurements of electrical resistivity, and dc susceptibility, and Hall coefficient. The onset superconducting transition temperature can reach 50 K at x = 0.2. The negative Hall coefficient at the studied temperature range suggests that the electron-type charge carriers are dominated, regardless of both electron and hole doping purposely designed. The complicated temperature dependence of R_{H} , is believed to be attributed to a multiband effect together with a complicated scattering, especially at low temperature near the T_c for such a binary doping system.

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471

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